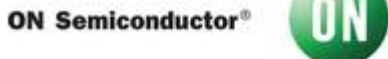




| | | |
|---|--|--|
|  | <h2 style="color: red;">NVB6413ANT4G</h2> | |
| | Hersteller-Teilenummer: | NVB6413ANT4G |
|  | Hersteller / Marke: | AMI Semiconductor / ON Semiconductor |
| | Teil der Beschreibung: | MOSFET N-CH 100V 40A D2PAK |
| Datenblätter: |  NVB6413ANT4G.pdf | |
| RoHs Status: | Bleifrei / RoHS-konform | |
| Lagerzustand: | New original, 1000 pcs Stock Available. | |
| Liefern von: | Hong Kong | |
| Versandweg: | DHL/Fedex/TNT/UPS/EMS | |
| <p>Image may be representation. See specs for product details.</p> | | |

Spezifikationen

| | |
|--|---|
| Teilenummer | NVB6413ANT4G |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET N-CH 100V 40A D2PAK |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 1000 pcs Stock |
| Serie | - |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 175°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB |
| Supplier Device-Gehäuse | D2PAK-3 |
| Verlustleistung (max) | 136W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 100V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 42A (Tc) |
| Rds On (Max) @ Id, Vgs | 28 mOhm @ 42A, 10V |
| VGS (th) (Max) @ Id | 4V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 51nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 1800pF @ 25V |
| Verpackung | Tape & Reel (TR) |

NVB6413ANT4G ist neu im Original, Suche NVB6413ANT4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NVB6413ANT4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NVB6413ANT4G: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|--|---|--|
|  <p>NVB5860NLT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 169A D2PAK</p> |  <p>NVB60N06T4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V D2PAK</p> |  <p>NVB6410ANT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 76A D2PAK</p> |  <p>NVB5860NT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 169A D2PAK</p> |
|  <p>NVBP Panduit VERTICAL BLANKING PANELS WITH PA</p> |  <p>NVB6412ANT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 59A D2PAK</p> |  <p>NVB5860N VB NVB5860N VB</p> |  <p>NVB6411ANT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 75A D2PAK</p> |

heiße Teile

Mehr

| | | | | |
|-----------------|---------------------|-------------------|------------------|------------------|
| 06035C102K4Z2A | 08051C122MAT2A | 08051C223MAT2A | D 1400SG50 | AP7311-15WG-7 |
| APT3D3216SRCPRV | AT25040AY1-10YU-1.8 | D ATECC108A-MAHUP | C8051F005 | CIC21J601NE |
| CP0805B0897CWTR | CX23416-12 | DG409DY-T1-E3 | G5NB-1A4-E-12VDC | LTC3586EUF#TRPBF |
| D LTM2881V-3 | LTV-355T-TP1 | M36W0T6050T3ZAQF | M74HCT244M1R | MA2SD320G8S0+ |
| MAX14575C | MAX3223CPP+ | MAZS120GML | MCH6536-TL-E | NCP502SQ18T1G |
| NVB25P06T4G | NVB5426NT4G | D NVB5860N | NVB5860NL | NVB5860NT4G |
| NVB60N06T4G | D NVB6410ANT4G | NVB6411ANT4G | NVB6412ANT4G | NVBF170LT1G |
| PSND150E/08 | PTV30B-E3/84A | S3F8278XZZ-ET88 | SI9122EDQ-T1-E3 | SM5S16A-E3/2D |
| SMLJ6.5ATR-13 | SMS7621-079LF | ST1200C18K2L | D STK672-110-E | TC4053BFT |
| TC74VHC244AF | TCLT1100 | TPS2071DAP | TPS54618AQR1BRQ1 | ZUS252412 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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